FMS2024

DC-20 GHz MMIC LOW LOSS SPDT ABSORPTIVE SWITCH

Low Insertion Loss: 1.4dB at

Excellent Low Control Voltage

High Isolation: 37dB at

All Reflective Design

Features

20GHz

20GHz

Package Style: Bare Die

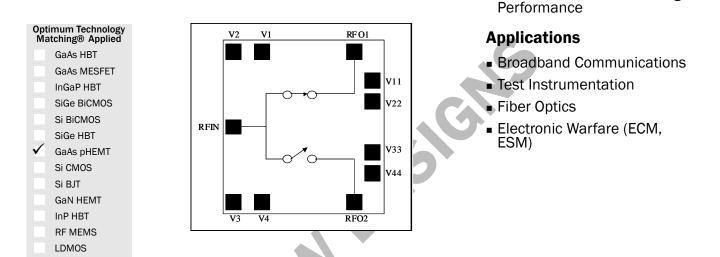


Product Description

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The FMS2024 is a low loss, high isolation broadband single-pole double-throw Gallium Arsenide switch, designed on the FL05 $0.5\mu m$ switch process from RFMD. It offers absorptive properties from the output (50 Ω termination). This process technology offers leading-edge performance optimized for switch applications.

The FMS2024 is developed for the broadband communications, instrumentation, and electronic warfare markets.



Parameter	Specification		Unit	Condition	
Falameter	Min. Typ.		Max.	Unit	Condition
Electrical Specifications					$T_{AMBIENT}$ =25 °C, V_{CTRL} =0V/-5V, Z_{IN} = Z_{OUT} =50 Ω
(Small-Signal Unless Noted)					
Insertion Loss	-1	-0.7		dB	DC
	-1.25	-0.85		dB	5GHz
	-1.6	-1.1		dB	10GHz
	-1.6	-1.2		dB	15GHz
	-1.8	-1.35		dB	20GHz
Isolation		-37	-34	dB	DC-20GHz
Input Return Loss		-14	-11	dB	DC-20GHz
Output Return Loss		-15	-11	dB	DC-20GHz
P1dB	23	28		dBm	2 GHz
	22	24		dBm	10GHz
	22	24		dBm	20GHz

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com.

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Absolute Maximum Ratings¹

Parameter	Rating	Unit
Maximum Input Power (P _{IN})	+27	dBm
Control Voltage (V _{CTRL})	+1/-10	V
Operating Temperature (T _{OPER})	-40 to 85	°C
Storage Temperature (T _{STOR})	-55 to 150	°C



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

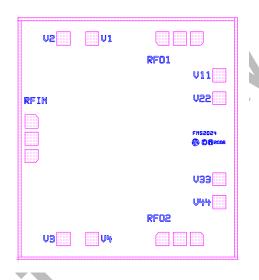
RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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Truth Table

Control Line			RF	Path	
V1 or V11	V2 or V22	V3 or V33	V4 or V44	RFIN-RF01	RFIN-RF02
-5V	OV	-5V	OV	On	Off
٥V	-5V	٥v	-5V	Off	On
٥V	-5V	-5V	OV	Off	Off

Notes: -5V±0.2V; -0V±0.2V; V11, V22, V33, and V44 are alternative control lines to V1, V2, V3, and V4 respectively.



Pad Layout

Pad	Description	Pin Coordinates (µm)
RFIN	RFIN	116, 1055
RF01	RFOUT1	1408, 1929
RF02	RFOUT2	1408, 181
V1	V1	645, 1929
V2	V2	395, 1929
V3	V3	395, 181
V4	V4	645, 181
V11	V11	1735, 1608
V22	V22	1753, 1408
V33	V33	1753, 702
V44	V44	1753, 502

Note: Coordinates are referenced from the bottom left hand corner of the die to the center of the bond pad opening.

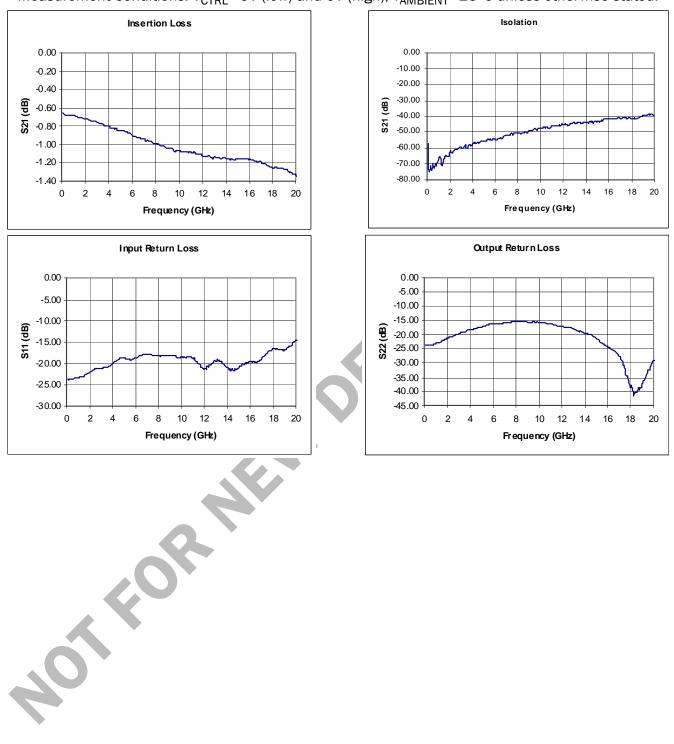
Die Size (µm)	Die Thickness (µm)	Min. Bond Pad Pitch (μ m)	Min. Bond Pad Opening ($\mu m x \mu m$)
1910x2110	100	150	116x116





Typical Measured Performance On Wafer

Measurement Conditions: V_{CTRL} = 5V (low) and OV (high), $T_{AMBIENT}$ = 25°C unless otherwise stated.



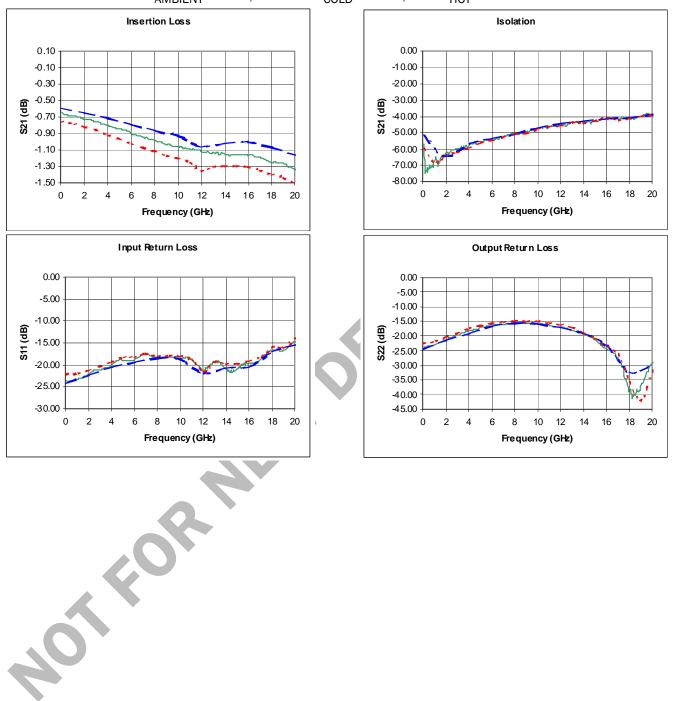




Typical Measured Performance On-Wafer Over Temperature

Measurement Conditions: V_{CTRL} =-5V (low) and OV (high).

 $T_{AMBIENT} = 25^{\circ}C, - - T_{COLD} = -40^{\circ}C, - - T_{HOT} = +85^{\circ}C$





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Preferred Assembly Instructions

GaAs devices are fragile and should be handled with great care. Specially designed collets should be used where possible.

The back of the die is metallized and the recommended mounting method is by the use of conductive epoxy. Epoxy should be applied to the attachment surface uniformly and sparingly to avoid encroachment of epoxy onto the top face of the die. Ideally it should not exceed half the chip height. For automated dispense Ablestick LMISR4 is recommended and for manual dispense Ablestick 84-1 LMI or 84-1 LMIT are recommended. These should be cured at a temperature of 150°C for one hour in an oven especially set aside for epoxy curing only. If possible the curing oven should be flushed with dry nitrogen. The gold-tin (80% Au 20% Sn) eutectic die attach has a melting point of approximately 280°C but the absolute temperature being used depends on the leadframe material used and the particular application. The maximum time at used should be kept to a minimum.

This part has gold (Au) bond pads requiring the use of gold (99.99% pure) bondwire. It is recommended that 25.4 mm diameter gold wire be used. Recommended lead bond technique is thermocompression wedge bonding with 0.001" (25µm) diameter wire. Bond force, time stage temperature and ultrasonics are all critical parameters and the settings are dependent on the setup and application being used. Ultrasonic or thermosonic bonding is not recommended.

Bonds should be made from the die first and then to the mounting substrate or package. The physical length of the bondwires should be minimized especially when making RF or ground connections.



Handling Precautions

To avoid damage to the devices, care should be exercised during handling. Proper Electrostatic Discharge (ESD) precautions should be observed at all stages of storage, handling, assembly, and testing.

ESD/MSL Rating

These devices should be treated as Class 1A (250V to 500V) using the human body model as defined in JEDEC Standard No. 22-A114. Further information on ESD control measures can be found in MIL-STD-1686 and MIL-HDBK-263. This is an unpackaged part and therefore no MSL rating applies.

Application Notes and Design Data

Application Notes and design data including S-parameters are available on request from www.rfmd.com.

Reliability

An MTTF of in excess of 9 million hours at a channel temperature of 150°C is achieved for the process used to manufacture this device.

Disclaimers

This product is not designed for use in any space-based or life-sustaining/supporting equipment.

Ordering Information

Delivery Quantity	Ordering Code
Full Pack (100)	FMS2024-000
Small Quantity (25)	FMS2024-000SQ
Small Quantity (3)	FMS2024-000S3